Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

2.125 inches

Terminal Length:

2.625 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.375 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1.1 forward voltage, peak

Current Rating Per Characteristic:

300.00 amperes forward current, average

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector nanoamperes

Maximum Operating Tempurature Per Measurement Point:

190.0 degrees celsius ambient air

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 insulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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